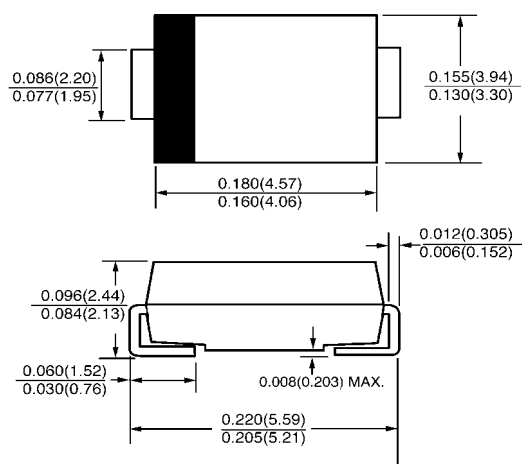


SURFACE MOUNT RECTIFIERS
VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 3.0 A
FEATURES

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-214AA, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.003 ounces, 0.093 grams
- ◇ Mounting position: Any

DO-214AA(SMB)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

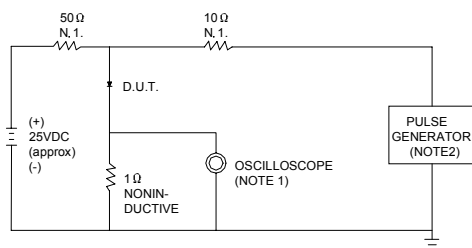
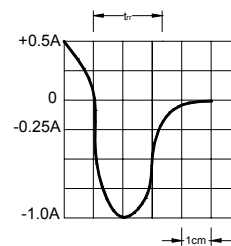
		UF3AB	UF3BB	UF3DB	UF3GB	UF3JB	UF3KB	UF3MB	UNITS
Device marking code		UA	UB	UD	UG	UJ	UK	UM	
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current @T _L =90°C	I _{F(AV)}	3.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	100.0							A
Maximum instantaneous forward voltage at 3.0 A	V _F	1.0			1.4	1.7			V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 200.0							μA
Typical reverse recovery time (Note1)	t _{rr}	50				75			ns
Typical junction capacitance (Note2)	C _J	15				12			pF
Typical thermal resistance (Note3)	R _{JA}	15.0							°C
Operating junction temperature range	T _J	- 55 ---- + 150							°C
Storage temperature range	T _{STG}	- 55 ---- + 150							°C

NOTE: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $t_{rr} = 0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

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FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = $1M\Omega \cdot 22pF$.
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω .

SET TIME BASE FOR 20/30 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

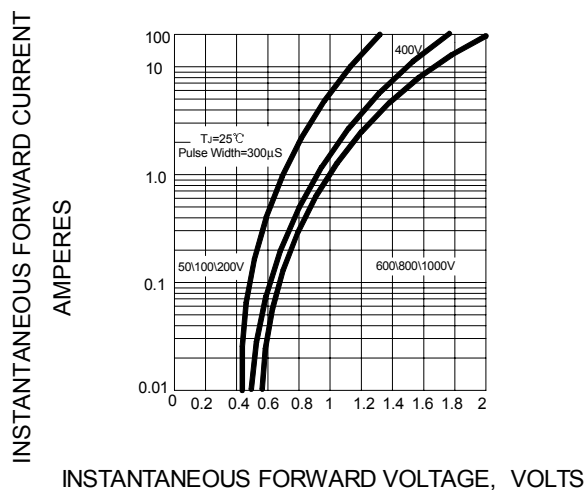


FIG.3 -- FORWARD DERATING CURVE

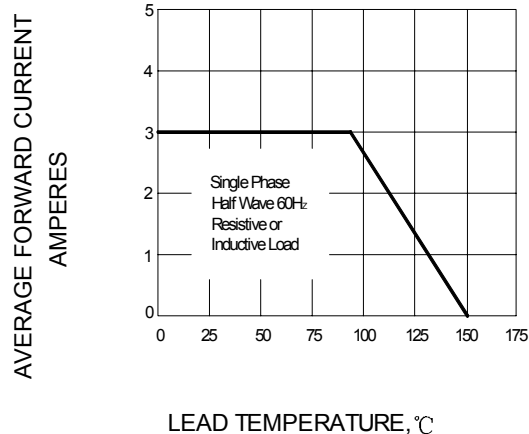


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

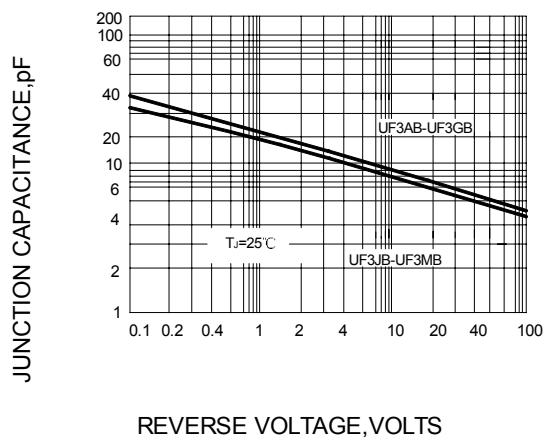


FIG.5 -- PEAK FORWARD SURGE CURRENT

